NSN 5962-00-222-6837

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View Online at https://aerobasegroup.com/nsn/5962-00-222-6837

Body Length:

Between 0.755 inches and 0.790 inches

Body Width:

Between 0.265 inches and 0.300 inches

Body Height:

Between 0.155 inches and 0.175 inches

Operating Tempurature Range:

+0.0/+70.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Type angyk3v coordinate data terminal

Features Provided:

Monolithic and hermetically sealed and positive outputs and w/storage and w/enable and schottky and w/decoded output and presettable

and programmable and w/open collector and programmed

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

10 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-1.5 volts power source and 5.5 volts power source

Time Rating Per Chacteristic:

30.00 nanoseconds propagation delay time, low to high level output and 30.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Test Data Document:

08241-1742-2874 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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- Demilitarization:

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